

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







1 Scope

The present specifications shall apply to Sanken silicon diode, RM4AM.

2 Outline

Туре	Silicon Rectifier Diode				
Structure	Resin Molded Flammability: UL94V-0 (Equivalent)				
Applications	Commercial Frequency Rectification				

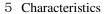
3 Absolute maximum ratings

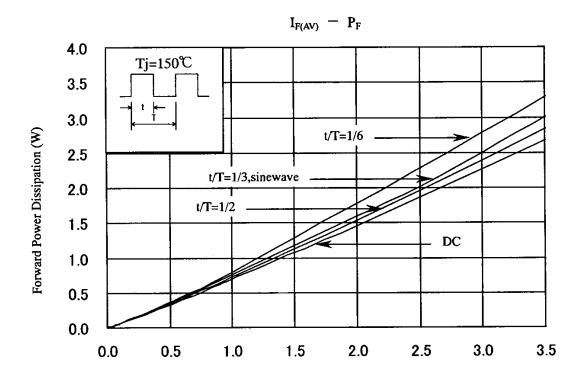
No.	Item	Symbol	Unit	Rating	Conditions
1	Transient Peak Reverse Voltage	V _{RSM}	V	650	
2	Peak Reverse Voltage	V_{RM}	V	600	
3	Average Forward Current	$I_{F(AV)}$	A	3.2	Refer to derating curve in Section 6
4	Peak Surge Forward Current	I_{FSM}	A	350	10ms. Half sine wave, one shot
5	I ² t Limiting Value	I^2t	A^2s	612.5	1ms≦≤10ms
6	Junction Temperature	T_{j}	°C	-40 to +150	
7	Storage Temperature	T_{stg}	°C	-40 to +150	

4 EElectrical characteristics (Ta=25°C, unless otherwise specified)

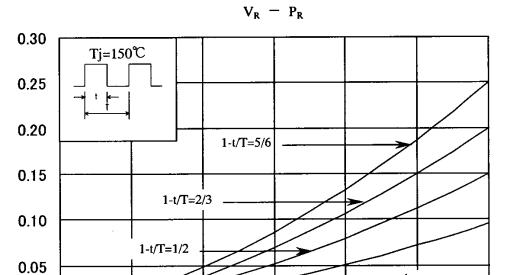
No.	Item	Symbol	Unit	Rating	Conditions
1	Forward Voltage Drop	V_{F}	V	0.92 max.	I _F =3.5A
2	Reverse Leakage Current	I_R	μA	10 max.	$V_R = V_{RM}$
3	Reverse Leakage Current Under High Temperature	$H \cdot I_R$	μA	50 max.	$V_R=V_{RM}, T_j=100^{\circ}C$
4	Thermal Resistance	R _{th(j-l)}	°C/W	8.0 max.	Between Junction and Lead

040817 1/4





Average Forward Current (A)



Reverse Voltage (V)

300

400

Reverse Power Dissipation (W)

0.00

0

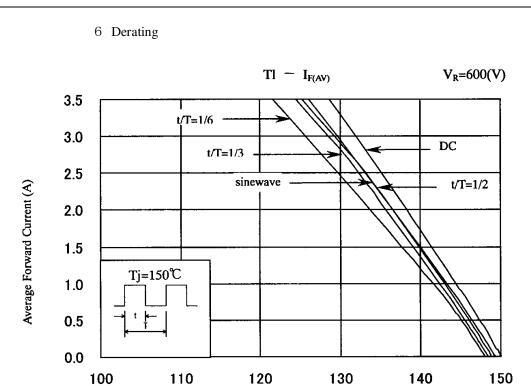
100

200

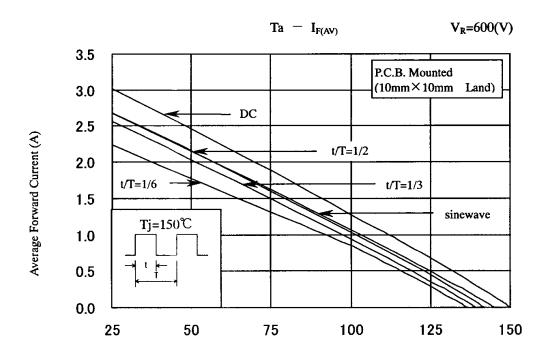
sinewave

500

600



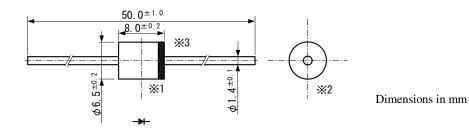
Lead Temperature (℃)



Ambient Temperature (℃)

7 Dimensions, inner structure and marking

7-1 Dimensions refer

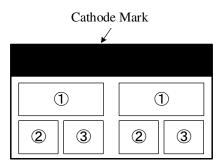


- *1 The allowance position of body against the center of whole lead wire is 0.5mm (max.)
- *2 The centric allowance of lead wire against center of physical body is 0.3mm (max.)
- *3 The burr may exist up to 2mm from the body of lead.

7-2Appearance

The body shall be clean and shall not bear any stain, rust or flaw. The color of the case will be black.

7-3 Marking



- ① Type number RM4AM
- 2 Lot number 1
 First digit: Last digit of Year
 Second digit: Month
 From 1 to 9 for Jan. to Sep.
 O for Oct., N for Nov., and D for Dec.
- ③Lot number 2 (ten days)
 - · Top of the month
 - · · Middle of month
 - · · · End of month